



Microsemi Corp.
The diode experts

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**1N957B
thru
1N992B
DO-7**

FEATURES

- 6.8 TO 200V ZENER VOLTAGE RANGE
- 1N962B THRU 1N992B HAVE JAN, JANTX AND JANTXV QUALIFICATIONS TO MIL-S-19500/117
- 1N962B THRU 1N973B HAVE S1N QUALIFICATION

MAXIMUM RATINGS

Steady State Power Dissipation: 400 mW
Operating and Storage Temperatures: -65°C to +175°C
Derating Factor Above 50°C: 3.2 mW/°C
Forward Voltage @ 200 mA: 1.5 Volts

**SILICON
400 mW
ZENER DIODES**

***ELECTRICAL CHARACTERISTICS @ 25°C**

JEDEC TYPE NUMBER (Note 1)	NOMINAL ZENER VOLTAGE (Note 2) Vz	ZENER TEST CURRENT IzT	MAX. ZENER IMPEDANCE (Note 3)			MAX. DC ZENER CURRENT (Note 4) IzM	MAX. SURGE ZENER CURRENT (RECURRENT) (Note 5) Iz (SURGE)	MAX. REVERSE LEAKAGE CURRENT		MAX. TEMP. COEFFICIENT Ckz
			Zz1 @ IzT	Zzk @ Izk	Ia			Vk		
	VOLTS	mA	OHMS	OHMS	mA	mA	μA	VOLTS	%/°C	
1N957B	6.8	18.5	4.5	700	1.0	55	300	150	5.2	+0.05
1N958B	7.5	16.5	5.5	700	.5	50	275	75	5.7	+0.058
1N959B	8.2	15.0	6.5	700	.5	45	250	50	6.2	+0.065
1N960B	9.1	14.0	7.5	700	.5	41	225	25	6.9	+0.068
1N961B	10	12.5	8.5	700	.25	38	200	10	7.6	+0.075
1N962B	11	11.5	9.5	700	.25	32	175	5	8.4	+0.076
1N963B	12	10.5	11.5	700	.25	31	160	5	9.1	+0.077
1N964B	13	9.5	13.0	700	.25	28	150	5	9.9	+0.079
1N965B	15	8.5	16	700	.25	25	130	5	11.4	+0.082
1N966B	16	7.8	17	700	.25	24	120	5	12.2	+0.083
1N967B	18	7.0	21	750	.25	20	110	5	13.7	+0.085
1N968B	20	6.2	25	750	.25	18	100	5	15.2	+0.086
1N969B	22	5.6	29	750	.25	16	90	5	16.7	+0.087
1N970B	24	5.2	33	750	.25	15	80	5	18.2	+0.088
1N971B	27	4.6	41	750	.25	13	70	5	20.6	+0.090
1N972B	30	4.2	49	1000	.25	12	65	5	22.8	+0.091
1N973B	33	3.8	58	1000	.25	11	60	5	25.1	+0.092
1N974B	36	3.4	70	1000	.25	10	55	5	27.4	+0.093
1N975B	39	3.2	80	1000	.25	9.5	46	5	29.7	+0.094
1N976B	43	3.0	93	1500	.25	8.8	44	5	32.7	+0.095
1N977B	47	2.7	105	1500	.25	7.9	40	5	35.8	+0.095
1N978B	51	2.5	125	1500	.25	7.4	37	5	38.8	+0.096
1N979B	56	2.2	150	2000	.25	6.8	35	5	42.6	+0.096
1N980B	62	2.0	185	2000	.25	6.0	30	5	47.1	+0.097
1N981B	68	1.8	230	2000	.25	5.5	28	5	51.7	+0.097
1N982B	75	1.7	270	2000	.25	5.0	26	5	56.0	+0.098
1N983B	82	1.5	330	3000	.25	4.6	23	5	62.2	+0.098
1N984B	91	1.4	400	3000	.25	4.1	21	5	69.2	+0.099
1N985B	100	1.3	500	3000	.25	3.7	18	5	76.0	+0.11
1N986B	110	1.1	750	4000	.25	3.3	16	5	83.5	+0.11
1N987B	120	1.0	900	4500	.25	3.1	15	5	91.2	+0.11
1N988B	130	0.95	1100	5000	.25	2.7	13	5	98.8	+0.11
1N989B	150	0.85	1500	6000	.25	2.4	12	5	114.0	+0.11
1N990B	160	0.80	1700	6500	.25	2.2	11	5	121.6	+0.11
1N991B	180	0.68	2200	7100	.25	2.0	10	5	136.8	+0.11
1N992B	200	0.65	2500	8000	.25	1.8	9	5	152.0	+0.11

*JEDEC Registered Data

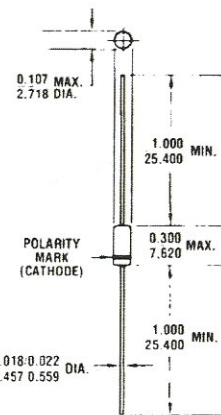


FIGURE 1

All dimensions in INCH m.m.

MECHANICAL CHARACTERISTICS

CASE: Hermetically sealed glass case, DO-7.

FINISH: All external surfaces are corrosion resistant and leads solderable.

THERMAL RESISTANCE: 300°C/W (Typical) junction to lead at 0.375-inches from body.

POLARITY: Diode to be operated with the banded end positive with respect to the opposite end.

WEIGHT: 0.2 grams.

MOUNTING POSITION: Any.

1N957B thru 1N992B DO-7

NOTE 1 The JEDEC type numbers shown (B suffix) have a $\pm 5\%$ tolerance on nominal zener voltage. The suffix A is used to identify $\pm 10\%$ tolerance; suffix C is used to identify $\pm 2\%$; and suffix D is used to identify $\pm 1\%$ tolerance; no suffix indicates $\pm 20\%$ tolerance.

NOTE 2 Zener voltage (V_Z) is measured after the test current has been applied for 20 ± 5 seconds. The device shall be suspended by its leads with the inside edge of the mounting clips between .375" and .500" from the body. Mounting clips shall be maintained at a temperature of $25 +8/-2^\circ\text{C}$.

NOTE 3 The zener impedance is derived from the 60 cycle A.C. voltage, which results when an A.C. current

having an R.M.S. value equal to 10% of the D.C. zener current (I_{ZT} or I_{ZK}) is superimposed on I_{ZT} or I_{ZK} . Zener impedance is measured at 2 points to insure a sharp knee on the breakdown curve and to eliminate unstable units.

NOTE 4 The values of I_{ZM} are calculated for a $\pm 5\%$ tolerance on nominal zener voltage. Allowance has been made for the rise in zener voltage above V_{ZT} which results from zener impedance and the increase in junction temperature as power dissipation approaches 400 mW. In the case of individual diodes I_{ZM} is that value of current which results in a dissipation of 400 mW at 50°C lead temperature at $3/8$ " from body.

NOTE 5 Surge is 1/2 square wave or equivalent sine wave pulse of 1/120 sec. duration.

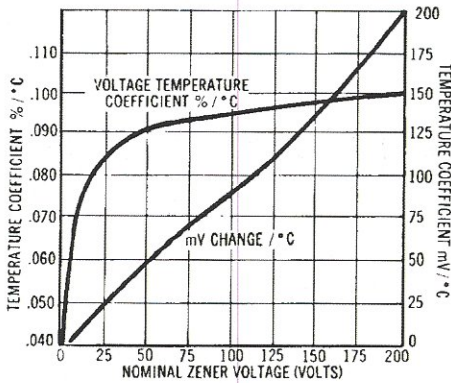


FIGURE 2
ZENER VOLTAGE TEMPERATURE
COEFF. vs. ZENER VOLTAGE

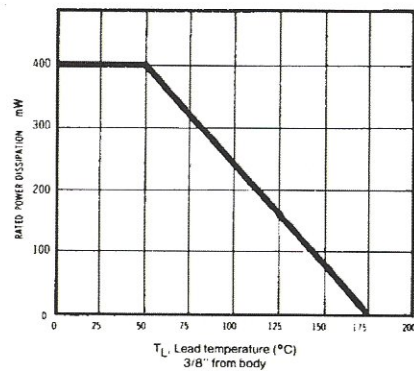


FIGURE 3
POWER DERATING CURVE

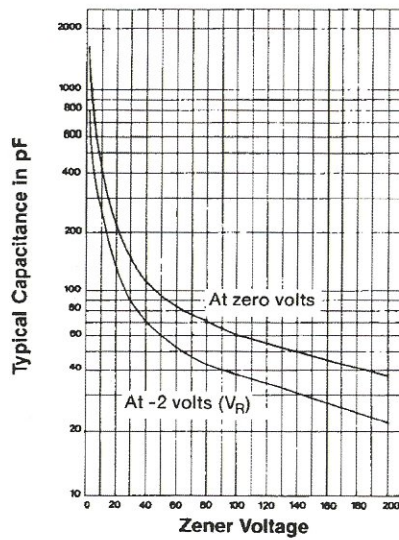


FIGURE 4
CAPACITANCE VS. ZENER VOLTAGE
(TYPICAL)